# NSN 5961-00-124-5019

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## Inclosure Material:

Metal

## **Overall Length:**

Between 0.240 inches and 0.260 inches

## **Terminal Length:**

1.500 inches

#### **Overall Diameter:**

Between 0.335 inches and 0.370 inches

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Pnp

**Mounting Method:** 

Terminal

#### Terminal Circle Diameter:

0.200 inches

#### **Features Provided:**

Hermetically sealed case

## Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

1.00 amperes collector current, dc

#### **Power Rating Per Characteristic:**

800.0 milliwatts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Terminal Type And Quantity:**

3 uninsulated wire lead

## **Specification Data:**

80131-release5174 professional/industrial association specification

Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

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